

High-performance Clock Generator Series

Compact 1ch Clock Generators for Digital Cameras

BU7344HFV,BU7345HFV,BU7346GUL

No.11005EAT06

RoHS

Description

These Clock Generators incorporates compact package compared to oscillators, which provides the generation of high-frequency CCD clocks necessary for digital still cameras and digital video cameras.

Features

- 1) SEL pin allowing for the selection of frequencies
- 2) Selection of OE (PDB) pin enabling Power-down function
- 3) Crystal-oscillator-level clock precision with high C/N characteristics and low jitter
- 4) Micro miniature Package incorporated
- 5) Single power supply of 3.3 V

Applications

Digital Still Camera, Digital Video Camera, and others

●Line up matrix

Parameter	BU7344HFV	BU7345HFV	BU7346GUL
Supply voltage	2.7V~3.6V	2.7V~3.6V	2.7V~3.6V
Operating temperature range	-5 ℃~75 ℃	-5 ℃~75 ℃	-5 ℃~75 ℃
Reference input clock	27.0000MHz	27.0000MHz	27.0000MHz
	40.5000MHz	38.0000MHz	38.0000MHz
Оцриї сюск	36.0000MHz	36.0000MHz	36.0000MHz
Standby current(MAX.)	1.0µA	1.0µA	1.0µA
Operating current (TYP)	4.0mA	3.5mA	3.5mA
Package	HVSOF6	HVSOF6	VCSP50L1 1.5mm×1.0mm

●Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Ratings	Unit
Supply voltage	VDD	-0.3 ~ 4.0	V
Input voltage	VIN	-0.3 ~ VDD+0.3	V
Storage temperature range	Tstg	-55 ~ 125	°C
Power discipation	Dd	410(BU7344HFV,BU7345HFV) ^{*1}	m\//
	FU	460(BU7346GUL) ^{*2}	IIIVV

*1 Mounted on 70mm * 70mm * 1.6mm Glass-epoxy PCB. Derating: 4.1mW / °C at Ta > 25°C
*2 Mounted on 50mm * 58mm * 1.75mm Glass-epoxy PCB. Derating: 4.6mW / °C at Ta > 25°C
* Operating is not guaranteed.

Operating is not guaranteed.

* The radiation-resistance design is not carried out.

Operating conditions

Parameter	Symbol	Ratings	Unit
Supply voltage	VDD	2.7 ~ 3.6	V
Input H voltage	VINH	0.8VDD ~ VDD	V
Input L voltage	VINL	0.0 ~ 0.2VDD	V
Operating temperature	Topr	-5 ~ 75	°C
Output load	CL	15(MAX.)	pF

Electrical characteristics

OBU7344HFV (Ta=25 °C, VDD=3.3V, Crystal frequency=27.0000MHz, unless otherwise specified.)

Doromotor	Symbol		Limits		Linit	Conditiona
Falameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Output H voltage	VOH	2.8	-	VDD	V	IOH = -3.0mA
Output L voltage	VOL	0.0	-	0.5	V	IOL = 3.0mA
Standby current	IDDst	-	-	1.0	μA	OE = L
Consumption current 1	IDD1	-	4.0	5.2	mA	40.5000MHz output SEL = L
Consumption current 2	IDD2	-	3.5	4.6	mA	36.0000MHz output SEL = H
Pull-down load	Rpd	50	100	200	kΩ	input PIN, pull-down load value
Output frequency						
OUT1	CLK40.5		40.5000		MHz	IN*12/4/2, SEL = L
OUT2	CLK36		36.0000		MHz	IN*8/3/2, SEL = H
* The output frequency is determine	ned by the arithm	atic (fraguancy	(division) ever	ossion of a from	nuency innu	t to IN

The output frequency is determined by the arithmetic (frequency division) expression of a frequency input to IN.

If the input frequency is set to 27.0000MHz, the output frequency will be as listed above.

OBU7345HFV (Ta=25 °C, VDD=3.3V, Crystal frequency=27.0000MHz, unless otherwise specified.)

Paramotor	Symbol		Limits		Linit	Conditions
Faianetei	Symbol	Min.	Тур.	Max.	Unit	Conditions
Output H voltage	VOH	2.8	-	VDD	V	IOH = -3.0mA
Output L voltage	VOL	0.0	-	0.5	V	IOL = 3.0mA
Standby current	IDDst	-	-	1.0	μA	OE = L
Consumption current 1	IDD1	-	3.5	4.6	mA	38.0000MHz output SEL = L
Consumption current 2	IDD2	-	3.5	4.6	mA	36.0000MHz output SEL = H
Pull-down load	Rpd	50	100	200	kΩ	input PIN, pull-down load value
Output frequency						
OUT1	CLK38		38.0000		MHz	IN*76/27/2, SEL = L
OUT2	CLK36		36.0000		MHz	IN*8/3/2, SEL = H

The output frequency is determined by the arithmetic (frequency division) expression of a frequency input to IN.

If the input frequency is set to 27.0000MHz, the output frequency will be as listed above.

OBU7346GUL (Ta=25 °C, VDD=3.3V, Crystal frequency=27.0000MHz, unless otherwise specified.)

Parameter	Symbol		Limits		Llnit	Conditions
Falanielei	Symbol	Min.	Тур.	Max.	Unit	Conditions
Output H voltage	VOH	2.8	-	VDD	V	IOH = -3.0mA
Output L voltage	VOL	0.0	-	0.5	V	IOL = 3.0mA
Standby current	IDDst	-	-	1.0	μA	PDB = L
Consumption current 1	IDD1	-	3.5	4.6	mA	38.0000MHz output SEL = L
Consumption current 2	IDD2	-	3.5	4.6	mA	36.0000MHz output SEL = H
Pull-down load	Rpd	50	100	200	kΩ	input PIN, pull-down load value
Output frequency						
OUT1	CLK38		38.0000		MHz	XIN*76/27/2, SEL = L
OUT2	CLK36		36.0000		MHz	XIN*8/3/2, SEL = H

The output frequency is determined by the arithmetic (frequency division) expression of a frequency input to XIN. If the input frequency is set to 27.0000MHz, the output frequency will be as listed above.

●Reference data (BU7344HFV basic data)





Fig.4 36MHz output waveform (CL=15pF,Ta=25 °C)

•Reference data (BU7345HFV basic data)



Fig.7 38MHz output waveform (CL=15pF,Ta=25 °C)



Fig.10 36MHz output waveform (CL=15pF,Ta=25 °C)



Fig.2 40.5MHz Period-Jitter (CL=15pF,Ta=25 °C)



Fig.5 36MHz Period-Jitter (CL=15pF,Ta=25 °C)



Fig.8 38MHz Period-Jitter (CL=15pF,Ta=25 °C)



Fig.11 36MHz Period-Jitter (CL=15pF,Ta=25 °C)





10kHz/div

Fig.9 38MHz spectrum (CL=15pF,Ta=25 °C)



Reference data (BU7346GUL basic data)







Fig.16 36MHz output waveform (CL=15pF,Ta=25 °C)



⊂(CL=15pF,Ta=25 °C)



Fig.17 36MHz Period-Jitter (CL=15pF,Ta=25 °C)



Fig.15 38MHz spectrum (CL=15pF,Ta=25 °C)



Fig.18 36MHz spectrum (CL=15pF,Ta=25 °C)

Reference data (BU7344HFV Temperature and Supply voltage variations data)



Fig.27 36MHz Temperature - Period-Jitter 1o





Temperature - Fall-time



Fig.26 36MHz Temperature - Fall-time



0

-25

0

25

50

temperature:T [°C]

Fig.25 36MHz

Temperature-Rise-time

75

100





5

4

3

2

1

0

Rise time:tr [nsec]

VDD=2.7V

VDD=3.6V

VDD=3.3V







Fig.31 38MHz Temperature - Fall-time



Fig.36 36MHz Temperature - Fall-time

50

temperature:T [°C]

25

VDD=2 7\ VDD=3.3

VDD=3.6V

75

100

300

200 100

0

-25

0

Fig.37 36MHz

Temperature - Period-Jitter 1o

Reference data (BU7346GUL Temperature and Supply voltage variations data)









Fig.41 38MHz Temperature-Fall-time



Fig.46 36MHz Temperature-Fall-time

25

VDD=3.6

75

100

50

temperature:T [°C]

Fig.48 36MHz

Temperature - Period-Jitter MIN-MAX

100

0

-25

0

Block diagram, pin assignment/functions

OBU7344HFV



6:IN

5:SEL

4:0E



Fig.49 Pin assignment

Fig.50 Block diagram

PIN No.	PIN Name	Function
1	VDD	Power supply
2	VSS	GND
3	OUT	Clock output terminal (SEL=L:40.5000MHz, SEL=H:36.0000MHz)
4	OE	Power-down pin (L:disable, H:enable), equipped with Pull-down function, output set to L at disable
5	SEL	Output selection (L:40.5000MHz, H:36.0000MHz)
6	IN	Clock input pin (27.0000MHz input)

OBU7345HFV





Fig.51 Pin assignment

Fig.52 Block diagram

PIN No.	PIN Name	Function
1	VDD	Power supply
2	VSS	GND
3	OUT	Clock output terminal (SEL=L:38.0000MHz, SEL=H:36.0000MHz)
4	OE	Power-down pin (L:disable, H:enable), equipped with Pull-down function, output set to L at disable
5	SEL	Output selection (L:38.0000MHz, H:36.0000MHz)
6	IN	Clock input pin (27.0000MHz input)

OBU7346GUL



PIN No.	PIN Name	Function
A1	XIN	Clock input pin (27.0000MHz input)
A2	SEL	Output selection (L:38.0000MHz, H:36.0000MHz)
A3	PDB	Power-down pin (L:disable, H:enable), equipped with Pull-down function, output set to L at disable
B1	VDD	Power supply
B2	VSS	GND
B3	OUT	Clock output terminal (SEL=L:38.0000MHz, SEL=H:36.0000MHz)

•Application circuit example



Fig.55 Application circuit example(BU7344HFV)

* For VDD and VSS, insert a bypass capacitor of approx. 0.1µF as close as possible to the pin.Bypass capacitors with good high-frequency characteristics are recommended. Even though we believe that the typical application circuit is worth of a recommendation, please be sure to thoroughly recheck the characteristics before use.

Equivalent circuit

Pin name	Pin number	Equivalent circuit
OUT	3, B3	From the inside of IC
OE(PDB) SEL	4, A2 5, A3	To the inside of IC
IN(XIN)	6, A1	From the inside of IC From the inside of IC

Appearance of Marker







marker

AA8

Notes for use

(1) Absolute Maximum Ratings

An excess in the absolute maximum ratings, such as applied voltage (VDD or VIN), operating temperature range (Topr), etc., can break down devices, thus making impossible to identify breaking mode such as a short circuit or an open circuit. If any special mode exceeding the absolute maximum ratings is assumed, consideration should be given to take physical safety measures including the use of fuses, etc.

(2) Recommended operating conditions

These conditions represent a range within which characteristics can be provided approximately as expected. The electrical characteristics are guaranteed under the conditions of each parameter.

(3) Reverse connection of power supply connector

The reverse connection of power supply connector can break down ICs. Take protective measures against the breakdown due to the reverse connection, such as mounting an external diode between the power supply and the IC's power supply terminal.

(4) Power supply line

Design PCB pattern to provide low impedance for the wiring between the power supply and the GND lines.

In this regard, for the digital block power supply and the analog block power supply, even though these power supplies has the same level of potential, separate the power supply pattern for the digital block from that for the analog block, thus suppressing the diffraction of digital noises to the analog block power supply resulting from impedance common to the wiring patterns. For the GND line, give consideration to design the patterns in a similar manner.

Furthermore, for all power supply terminals to ICs, mount a capacitor between the power supply and the GND terminal. At the same time, in order to use an electrolytic capacitor, thoroughly check to be sure the characteristics of the capacitor to be used present no problem including the occurrence of capacity dropout at a low temperature, thus determining the constant.

(5) GND voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state. Furthermore, check to be sure no terminals are at a potential lower than the GND voltage including an actual electric transient.

(6) Short circuit between terminals and erroneous mounting

In order to mount ICs on a set PCB, pay thorough attention to the direction and offset of the ICs. Erroneous mounting can break down the ICs. Furthermore, if a short circuit occurs due to foreign matters entering between terminals or between the terminal and the power supply or the GND terminal, the ICs can break down.

(7) Operation in strong electromagnetic field

Be noted that using ICs in the strong electromagnetic field can malfunction them.

(8) Inspection with set PCB

On the inspection with the set PCB, if a capacitor is connected to a low-impedance IC terminal, the IC can suffer stress. Therefore, be sure to discharge from the set PCB by each process. Furthermore, in order to mount or dismount the set PCB to/from the jig for the inspection process, be sure to turn OFF the power supply and then mount the set PCB to the jig. After the completion of the inspection, be sure to turn OFF the power supply and then dismount it from the jig. In addition, for protection against static electricity, establish a ground for the assembly process and pay thorough attention to the transportation and the storage of the set PCB.

(9) Input terminals

In terms of the construction of IC, parasitic elements are inevitably formed in relation to potential. The operation of the parasitic element can cause interference with circuit operation, thus resulting in a malfunction and then breakdown of the input terminal. Therefore, pay thorough attention not to handle the input terminals, such as to apply to the input terminals a voltage lower than the GND respectively, so that any parasitic element will operate. Furthermore, do not apply a voltage to the input terminals when no power supply voltage is applied to the IC. In addition, even if the power supply voltage is applied, apply to the input terminals a voltage lower than the power supply voltage or within the guaranteed value of electrical characteristics.

(10) Ground wiring pattern

If small-signal GND and large-current GND are provided, It will be recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause no fluctuations in voltages of the small-signal GND. Pay attention not to cause fluctuations in the GND wiring pattern of external parts as well.

(11) External capacitor

In order to use a ceramic capacitor as the external capacitor, determine the constant with consideration given to a degradation in the nominal capacitance due to DC bias and changes in the capacitance due to temperature, etc.

Ordering part number



VCSP50L1(BU7346GUL)



	Notes
N c	lo copying or reproduction of this document, in part or in whole, is permitted without the onsent of ROHM Co.,Ltd.
Т	he content specified herein is subject to change for improvement without notice.
T "I W	he content specified herein is for the purpose of introducing ROHM's products (hereinafter Products"). If you wish to use any such Product, please be sure to refer to the specifications, rhich can be obtained from ROHM upon request.
E ill b	xamples of application circuits, circuit constants and any other information contained herein lustrate the standard usage and operations of the Products. The peripheral conditions must e taken into account when designing circuits for mass production.
G H ir	areat care was taken in ensuring the accuracy of the information specified in this document. lowever, should you incur any damage arising from any inaccuracy or misprint of such nformation, ROHM shall bear no responsibility for such damage.
T ir o u	he technical information specified herein is intended only to show the typical functions of and xamples of application circuits for the Products. ROHM does not grant you, explicitly or nplicitly, any license to use or exercise intellectual property or other rights held by ROHM and ther parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the se of such technical information.
T e n	he Products specified in this document are intended to be used with general-use electronic quipment or devices (such as audio visual equipment, office-automation equipment, commu- ication devices, electronic appliances and amusement devices).
Т	he Products specified in this document are not designed to be radiation tolerant.
۷ P	While ROHM always makes efforts to enhance the quality and reliability of its Products, a product may fail or malfunction for a variety of reasons.
P a fa s	lease be sure to implement in your equipment using the Products safety measures to guard gainst the possibility of physical injury, fire or any other damage caused in the event of the ailure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM hall bear no responsibility whatsoever for your use of any Product outside of the prescribed cope or not in accordance with the instruction manual.
T s ir c o s	he Products are not designed or manufactured to be used with any equipment, device or ystem which requires an extremely high level of reliability the failure or malfunction of which hay result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel- ontroller or other safety device). ROHM shall bear no responsibility in any way for use of any f the Products for the above special purposes. If a Product is intended to be used for any uch special purpose, please contact a ROHM sales representative before purchasing.
b o	e controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to btain a license or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/